

1036 U.S. PTO
10/034221

12/28/01

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U.S. UTILITY Patent Application

PATENT NUMBER and
ISSUE DATE

APPL NUM 10034221	FILING DATE 12/28/2001	CLASS 438	SUBCLASS 94	GAU 2812	EXAMINER Anderson
**APPLICANTS: Pyi Seung; 1.7 1.765					
ABANDONED					
**CONTINUING DATA VERIFIED:					
** FOREIGN APPLICATIONS VERIFIED: REPUBLIC OF KOREA 2001-67090 10/30/2001					
PG-PUB <input type="checkbox"/> DO NOT PUBLISH <input type="checkbox"/>		RESCIND <input type="checkbox"/>			
Free in priority claimed <input type="checkbox"/> yes <input type="checkbox"/> no		35 USC 119 conditions met <input type="checkbox"/> yes <input type="checkbox"/> no		ATTORNEY DOCKET NO	
Verified and Acknowledged Examiners's initials				CU-2755 VE	
TITLE : Method for fabricating a semiconductor epitaxial wafer having doped carbon and a semiconductor epitaxial wafer					
U.S. DEPT. OF COMM/PAT & TM-PTO-436L (Rev. 12-94)					

NOTICE OF ALLOWANCE MAILED		CLAIMS ALLOWED	
		Total Claims	Print Claim for O.G
Assistant Examiner		DRAWING	
ISSUE FEE		Sheets Drwg.	Figs. Drwg.
Amount Due	Date Paid	Print Fig.	
Primary Examiner		Application Examiner	
<input type="checkbox"/> TERMINAL DISCLAIMER		PREPARED FOR ISSUE	
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